

# IPP072N10N3GHKSA1

## IPP072N10N3GHKSA1 Information

www.heiseper.com	 IPP072N10N3GHKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 100V 80A TO220-3 TO-220-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# IPP072N10N3GHKSA1 Specifications

Manufacturer Part Number	IPP072N10N3GHKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3.5V @ 90µA
Gate Charge (Qg) (Max) @ Vgs	68nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4910pF @ 50V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	150W (Tc)
Rds On (Max) @ Id, Vgs	7.2 mOhm @ 80A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

### IPP072N10N3GHKSA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### IPP072N10N3GHKSA1 Payment Methods





If you have any question about IPP072N10N3GHKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com